

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error	Errors
1	BRS	44	dram and capacitor and (hsg or hemispher\$) with nitride and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 23:34			0
2	BRS	11	dram and capacitor and (hsg or hemispher\$) with nitride and fill\$ with \$resist and peroxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:54			0
3	BRS	11	dram and capacitor and (hsg or hemispher\$) with nitride and fill\$ with \$resist and peroxide and (ammonia or ammonium or nh4oh)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:55			0
4	BRS	12	dram and capacitor and (hsg or hemispher\$) with nitride with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 23:15			0
5	BRS	44	dram and capacitor and (hsg or hemispher\$) with nitride and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 23:34			0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Ratio
6	BRS	126	dram and capacitor and (hsg or hemispher\$) with nitride and \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 23:57		0
7	BRS	6	dram and capacitor and (hsg or hemispher\$ or rugg\$ or rough\$) near nitride and \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 23:59		0
8	BRS	101	dram and capacitor and (hsg or hemispher\$ or rugg\$ or rough\$) near5 nitride and \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 23:59		0
9	BRS	53	dram and capacitor and (hsg or hemispher\$ or rugg\$ or rough\$) near3 nitride and \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 00:01		0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Corrections
10	BRS	11	dram and capacitor and (hsg or hemispher\$ or rugg\$ or rough\$) with (cavity or trench or hole or opening) and nitride and \$resist with fill\$ with (cavity or trench or opening or hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 00:04		0
11	BRS	22	dram and capacitor and (hsg or hemispher\$ or rugg\$ or rough\$) with (cavity or trench or hole or opening) and nitride with (hsg or hemispher\$ or rugg\$ or rough\$) and \$resist with fill\$ with (cavity or trench or opening or hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:11		0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error	Errors
12	BRS	8	dram and capacitor and (hsg or hemispher\$ or rugg\$ or rough\$) with (cavity or trench or hole or opening) and nitride with \$resist with reces\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:27			0
13	BRS	6	dram and capacitor and (titanium adj nitride or tin) with \$resist with reces\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:34			0
14	BRS	6	dram and capacitor and (metal adj nitride or tin) with \$resist with reces\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:36			0
15	BRS	9	capacitor and (metal adj nitride or tin) with \$resist with reces\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:42			0
16	BRS	25	(metal adj nitride or tin) with \$resist with reces\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:45			0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error	Errors
17	BRS	17	(nitride or tin) with \$resist with (ammoni\$ or nh or \$chloric or \$9chloride or hcl) with \$peroxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:55			0
18	BRS	13	nitride with \$resist with (ammoni\$ or nh or \$chloric or \$9chloride or hcl) with \$peroxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 13:55			0
19	BRS	17	(nitride or tin or wn or tan) with \$resist with (ammoni\$ or nh or \$chloric or \$9chloride or hcl) with \$peroxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 14:03			0
20	BRS	77	(nitride or tin or wn or tan) with \$resist with select\$9 with (etch\$ or reces\$) and (ammoni\$ or nh or \$chloric or \$9chloride or hcl) with \$peroxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 14:36			0
21	BRS	3	"5071510" "6083849" "6261964").PN.	USPAT	2004/10/27 14:25			0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error
22	BRS	75	(nitride or tin or wn or tan) with (lower or storage) with electrode and \$resist with select\$9 with (etch\$ or reces\$) and capacitor and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:28		0
23	BRS	99	(nitride or tin or wn or tan) with (lower or storage or bottom) with electrode and \$resist with select\$9 with (etch\$ or reces\$) and capacitor and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:31		0
24	BRS	1	(nitride or tin or wn or tan) near (lower or storage or bottom) near electrode and \$resist with select\$9 with (etch\$ or reces\$) and capacitor and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:29		0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Info
25	BRS	66	(nitride or tin or wn or tan) with (lower or storage or bottom) with electrode and \$resist with select\$9 with (etch\$ or reces\$) and capacitor and fill\$ with \$resist with (trench or cavity or hole or recess)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:35		0
26	BRS	15	(nitride or tin or wn or tan) with (lower or storage or bottom) with electrode and \$resist with select\$9 with (etch\$ or reces\$) and capacitor and fill\$ with \$resist with (trench or cavity or hole or recess) and electrode with lower with fill\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:37		0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Corrections
27	BRS	6	dram and capacitor near (container or cup or trench) and nitride near electrode and fill\$ near \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:47		0
28	BRS	11 4	dram and capacitor near (container or cup or trench) and nitride with electrode and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:49		0
29	BRS	6	dram and capacitor near (container or cup or trench) and nitride near electrode and fill\$ with \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:49		0
30	BRS	40	dram and capacitor near (container or cup or trench) and nitride with electrode and fill\$ near \$resist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/27 15:50		0